

635 nm Laser Diode, 5 mW

HL6312G



Description

This 635 nm, 5 mW TO packaged laser diode is a compact light source that outputs a single transverse mode and is suited for a variety of applications such as a laser level, bar code reader, distance meter, or a light source for optical equipment. It is packaged in a standard Ø9 mm TO can package and has an A pin configuration. This laser diode is compatible with our line of laser diode and TEC controllers as well as our selection of collimation solutions and TO can laser diode mounts.

Specifications

Absolute Maximum Ratings ^a				
Specification	Maximum			
Optical Output Power, CW	5 mW			
LD Reverse Voltage	2 V			
PD Reverse Voltage	30 V			
Operating Temperature	-10 °C to 50 °C			
Storage Temperature	-40 °C to 85 °C			



a. Absolute Maximum Rating specifications should never be exceeded. Operating at or beyond these conditions can permanently damage the laser.

HL6312G Specifications ^a						
		Symbol	Min	Typical	Max	
Center Wavelength @ Popb		λο	625 nm	635 nm	640 nm	
Threshold Current		I _{TH}	-	40 mA	70 mA	
Operating Current, CW @ P _{op} ^b		I _{op}	-	50 mA	85 mA	
Operating Voltage @ Popb		V_{op}	-	-	2.7 V	
Slope Efficiency		η	-	0.4 mW/mA	-	
Astigmatism @ P _{op} ^b		A_s	-	8 µm	-	
Beam Divergence (FWHM) @ P _{op} b	Parallel	θ//	5°	8°	11°	
	Perpendicular	$oldsymbol{ heta}_{\perp}$	25°	31°	37°	
Monitor Current @ Popb		I_{PD}	0.15 mA	0.25 mA	0.8 mA	

a. $T_{CASE} = 25$ °C if not specified.

b. $P_{op} = 5 \text{ mW}$



Drawing





